ES1A THRU ES1J

SURFACE MOUNT SUPERFAST RECOVERY RECTIFIER

Reverse Voltage - 50 to 600 V Forward Current - 1 A

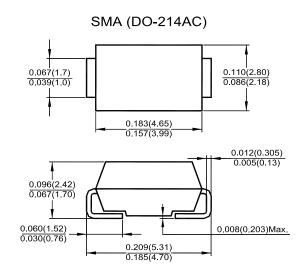
Features

- Plastic package has Underwriters Laboratories Flammability Classification 94V-0
- Easy pick and place
- For surface mounted applications
- Low profile package
- Built-in strain relief
- Superfast recovery times for high efficiency

Mechanical Data

• Case: SMA (DO-214AC), molded plastic • Terminals: Solder plated, solderable per MIL-STD-750, Method 2026 guaranteed

• Polarity: Color band denotes cathode end



Dimensions in inches and (millimeters)

Absolute Maximum Ratings and Characteristics

Ratings at 25°C ambient temperature unless otherwise specified. Single phase, half wave, 60 Hz, resistive or inductive load. For capacitive load, derate current by 20%.

To capacitive load, derate current by 2070.									
Parameter	Symbols	ES1A	ES1B	ES1C	ES1D	ES1E	ES1G	ES1J	Units
Maximum Recurrent Peak Reverse Voltage	V_{RRM}	50	100	150	200	300	400	600	V
Maximum RMS Voltage	V_{RMS}	35	70	105	140	210	280	420	V
Maximum DC Blocking Voltage	V_{DC}	50	100	150	200	300	400	600	V
Maximum Average Forward Rectified Current T _L = 100 °C	I _{F(AV)}	1							Α
Peak Forward Surge Current 8.3 ms Single Half Sine Wave Superimposed on Rated Load (JEDEC Method)	I _{FSM}	30							А
Maximum Forward Voltage at 1 A	V _F	0.95				1.:	25	1.7	V
	I _R	5 100							μΑ
Typical Junction Capacitance at $V_R = 4 \text{ V}$, $f = 1 \text{ MH}_Z$	CJ	10						pF	
Typical Reverse Recovery Time at $I_F = 0.5 \text{ A}$, $I_R = 1 \text{ A}$, $I_{rr} = 0.25 \text{ A}$	t _{rr}	35 50						50	ns
Typical Thermal Resistance 1)	$R_{\theta JL}$	35							°C/W
Operating Junction and Storage Temperature Range	T _J ,T _S	- 55 to + 150							°C

¹⁾ Thermal resistance from junction to lead mounted on P.C.B. with 0.3 X 0.3" (8.0 X 8.0 mm) copper pad areas.

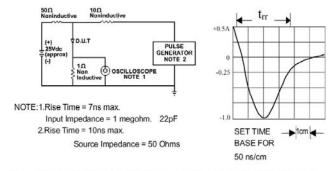








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SINGLE PHASE HALF WAVE RESISTIVE OR INDUCTIVE P.C.B MOUNTED ON AVERAGE FORWARD CURRENT AMPERES 0.315×0.315*(8.0×8.0mm) PAD AREAS LEAD TEMPERATURE, "C

Fig. 1-REVERSE RECOVERY TIME CHARACTERISTIC AND TEST CIRCUIT DIAGRAM

Fig. 2-MAXIMUM AVERAGE FORWARD **CURRENT RATING**

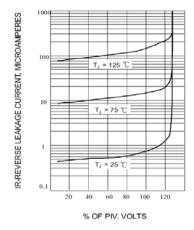


Fig. 3-TYPICAL REVERSE CHARACTERISTICS

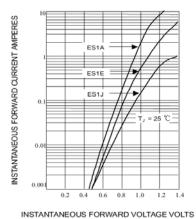


Fig. 4-TYPICAL FORWARD CHARACTERISTICS

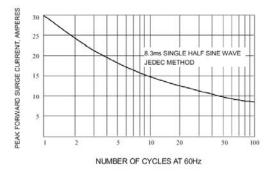


Fig. 5-MAXIMUM NON-REPETITIVE SURGE CURRENT

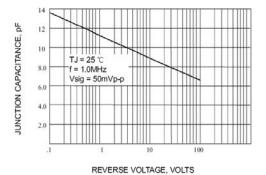


Fig. 6-TYPICAL JUNCTION CAPACITANCE



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Dated: 14/04/2008 H